

SN75ALS174 Quadruple Differential Line Driver

1 Features

- Meets or exceeds the requirements of ANSI EIA/TIA-422-B and RS-485
- High-speed advanced low-power Schottky circuitry
- Designed for up to 20-Mbit/s operation in both serial and parallel applications
- Designed for multipoint transmission on long bus lines in noisy environments
- Low supply current requirements 55 mA max
- Wide positive and negative input/output bus voltage ranges
- Driver output capacity: 60 mA
- Thermal-shutdown protection
- Driver positive- and negative-current limiting

2 Applications

- [Motor drives](#)
- [Factory automation and control](#)

3 Description

The SN75ALS174 is a quadruple line driver with tri-state differential outputs. It is designed to meet the requirements of ANSI Standards EIA/TIA-422-B and RS-485. This device is optimized for balanced multipoint bus transmission at rates of up to 20 Mbit/s.

Each driver features wide positive and negative common-mode output voltage ranges that make them suitable for party-line applications in noisy environments.

The SN75ALS174 provides positive- and negative-current limiting and thermal shutdown for protection from line fault conditions on the transmission bus line. Shutdown occurs at a junction temperature of approximately 150°C.

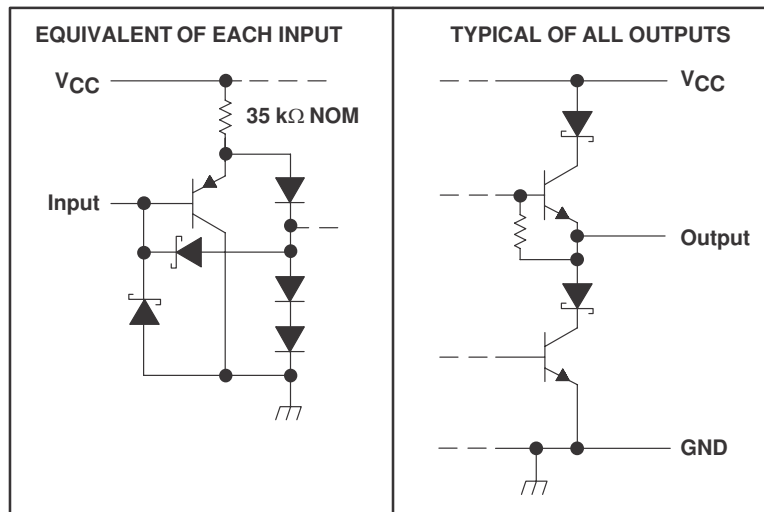
The SN75ALS174 is characterized for operation from 0°C to 70°C.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
SN75ALS174	SOIC (DW, 20)	12.8 mm × 10.3 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

(2) The package size (length × width) is a nominal value and includes pins, where applicable.



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Schematics of Inputs and Outputs



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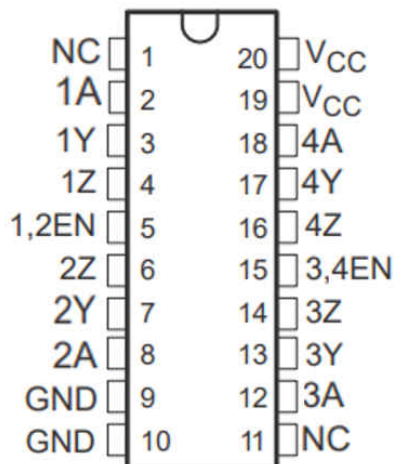
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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
June 2023	*	Initial Release

5 Pin Configuration and Functions



NC – No internal connection

DW (SOIC) Package (Top View)

Table 5-1. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
V _{CC}	19, 20	VCC	5-V supply. These pins are not connected together internally, so power must be applied to both
GND	9, 10	GND	Device ground
NC	1, 11	NC	Internally not connected
1A	2	I	Driver data input
1Y	3	O	Bus output, Y (Complementary to Z)
1Z	4	O	Bus output, Z (Complementary to Y)
1,2EN	5	I	Driver enable, active high
2Z	6	O	Bus output, Z (Complementary to Y)
2Y	7	O	Bus output, Y (Complementary to Z)
2A	8	I	Driver data input
3A	12	I	Driver data input
3Y	13	O	Bus output, Y (Complementary to Z)
3Z	14	O	Bus output, Z (Complementary to Y)
3,4EN	15	I	Driver enable, active high
4Z	16	O	Bus output, Z (Complementary to Y)
4Y	17	O	Bus output, Y (Complementary to Z)
4A	18	I	Driver data input

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	MIN	MAX	UNIT
Supply voltage, V_{CC} ⁽²⁾		7	V
Input voltage, V_I		7	V
Output voltage range, V_O	–9	14	V
Continuous total dissipation	See the <i>Dissipation Rating</i> table		
Storage temperature, T_{stg}	–65	150	°C

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) All voltage values are with respect to network GND.

6.2 Dissipation Rating Table

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
DW	1125 mW	9.0 mW/°C	720 mW	596 mW

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	4.75	5	5.25	V
V_{IH}	High-level input voltage	2			V
V_{IL}	Low-level input voltage			0.8	V
V_{OC}	Common-mode output voltage			12	V
				–7	V
I_{OH}	High-level output current			–60	mA
I_{OL}	Low-level output current			60	mA
T_A	Operating free-air temperature	0		70	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		DW (SOIC)	UNIT
		20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	57.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	25.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	25.3	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	4.7	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	25.0	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V_{IK} Input clamp voltage	$I_I = -18\text{ mA}$			-1.5	V
V_O Output voltage	$I_O = 0$	0		6	V
$ V_{OD1} $ Differential output voltage	$I_O = 0$	1.5		6	V
$ V_{OD2} $ Differential output voltage	$R_L = 100\ \Omega$	$1/2 V_{OD1}$ or 2 ⁽²⁾			V
	$R_L = 54\ \Omega$	1.5	2.5	5	V
$ V_{OD3} $ Differential output voltage	See ⁽⁵⁾	1.5		5	V
$\Delta V_{OD} $ Change in magnitude of differential output voltage ⁽³⁾	$R_L = 54\ \Omega$ or $100\ \Omega$	See Figure 7-1			± 0.2 V
V_{OC} Common-mode output voltage ⁽⁴⁾	$R_L = 54\ \Omega$ or $100\ \Omega$	See Figure 7-1			3 V
					-1 V
$\Delta V_{OC} $ Change in magnitude of common-mode output voltage ⁽³⁾	$R_L = 54\ \Omega$ or $100\ \Omega$	See Figure 7-1			± 0.2 V
I_O Output current with power off	$V_{CC} = 0$, $V_O = -7\text{ V to }12\text{ V}$			± 100	μA
I_{OZ} High-impedance-state output current	$V_O = -7\text{ V to }12\text{ V}$			± 100	μA
I_{IH} High-level input current	$V_I = 2.7\text{ V}$			20	μA
I_{IL} Low-level input current	$V_I = 0.4\text{ V}$			-100	μA
I_{OS} Short-circuit output current	$V_O = -7\text{ V to }12\text{ V}$			± 250	mA
I_{CC} Supply current (all drivers)	No load	Outputs enabled	36	55	mA
		Outputs disabled	16	30	mA

(1) All typical values are at $V_{CC} = 5\text{ V}$ and $T_A = 25^\circ\text{C}$.

(2) The minimum V_{OD2} with a $100\text{-}\Omega$ load is either $1/2 V_{OD1}$ or 2 V , whichever is greater.

(3) $\Delta|V_{OD}|$ and $\Delta|V_{OC}|$ are the changes in magnitude of V_{OD} and V_{OC} , respectively, that occur when the input is changed from a high level to a low level.

(4) In ANSI Standard EIA/TIA-422-B, V_{OC} , which is the average of the two output voltages with respect to ground, is called output offset voltage, V_{OS} .

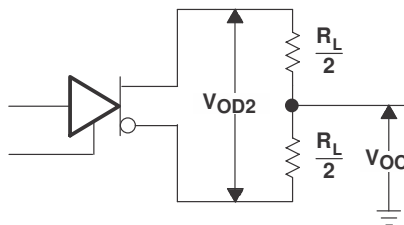
(5) See EIA Standard RS-485, Figures 3-5, Test Termination Measurement 2.

6.6 Switching Characteristics

over operating free-air temperature range (unless otherwise noted), $C_L = 50\text{ pF}$

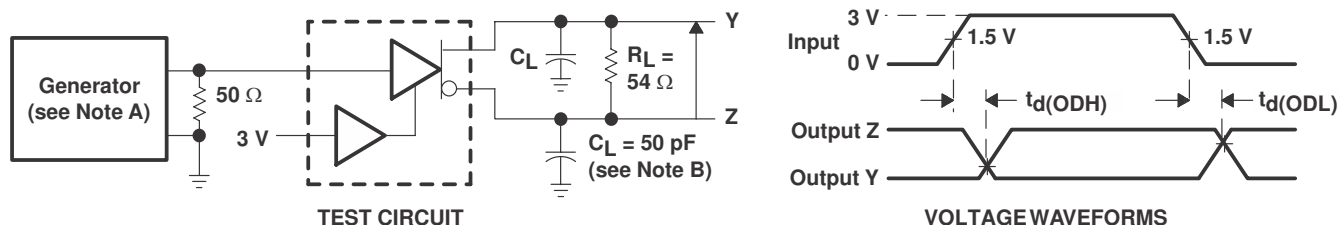
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{d(OD)}$ Differential output delay time	$R_L = 54\ \Omega$, See Figure 7-2	9	15	22	ns
t_{PZH} Output enable time to high level	$R_L = 110\ \Omega$, See Figure 7-3	30	45	70	ns
t_{PZL} Output enable time to low level	$R_L = 110\ \Omega$, See Figure 7-4	25	40	65	ns
t_{PHZ} Output disable time from high level	$R_L = 110\ \Omega$, See Figure 7-3	10	20	35	ns
t_{PLZ} Output disable time from low level	$R_L = 110\ \Omega$, See Figure 7-4	10	30	45	ns

7 Parameter Measurement Information



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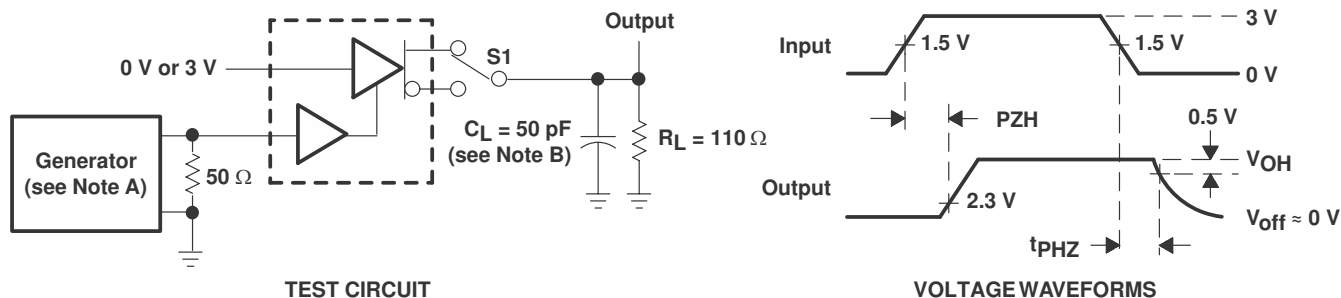
Figure 7-1. Differential and Common-Mode Output Voltages



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- A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, $Z_O = 50\ \Omega$, duty cycle = 50%, t_r 5 ns, t_f 5 ns.
- B. C_L includes probe and stray capacitance.

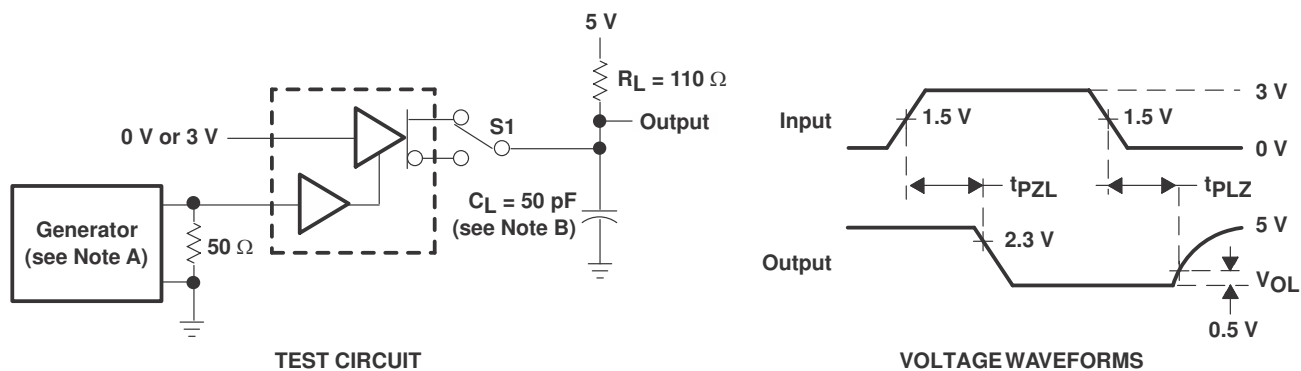
Figure 7-2. Differential-Output Test Circuit and Delay and Transition Times Voltage Waveforms



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- A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, $Z_O = 50\ \Omega$, duty cycle = 50%, t_r 5 ns, t_f 5 ns.
- B. C_L includes probe and stray capacitance.

Figure 7-3. Test Circuit and Voltage Waveforms, t_{PZH} and t_{PHZ}



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- A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, $Z_O = 50 \Omega$, duty cycle = 50%, t_f 5 ns, t_r 5 ns.
- B. C_L includes probe and stray capacitance.

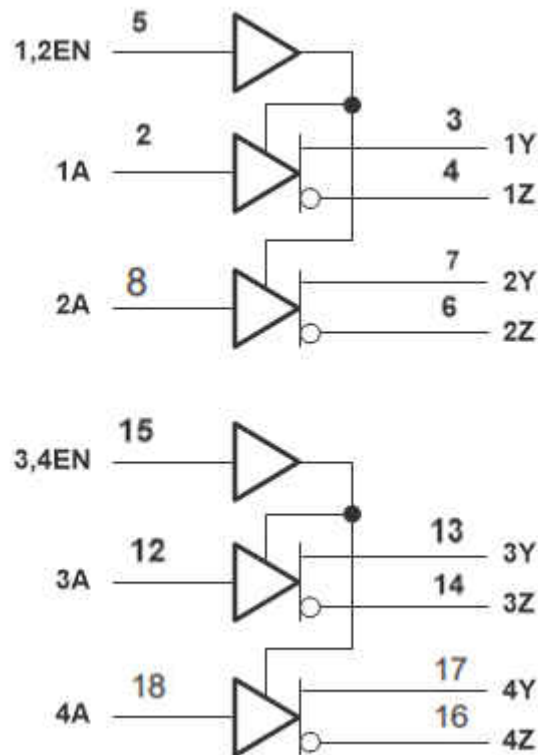
Figure 7-4. Test Circuit and Voltage Waveforms, t_{PZL} and t_{PLZ}

8 Detailed Description

8.1 Overview

The SN75ALS174 is a quadruple line driver with tristate differential outputs. It is designed to meet the requirements of ANSI Standards EIA/TIA-422-B and RS-485. This device is optimized for balanced multipoint bus transmission at rates of up to 20 Mbit/s

8.2 Functional Block Diagram



8.3 Feature Description

Each driver features wide positive and negative common-mode output voltage ranges that make them suitable for party-line applications in noisy environments. The SN75ALS174 provides positive- and negative-current limiting and thermal shutdown for protection from line fault conditions on the transmission bus line. Shutdown occurs at a junction temperature of approximately 150°C

8.4 Device Functional Modes

Table 8-1. Function Table (each driver)

INPUT A ⁽¹⁾	ENABLES	OUTPUTS ⁽²⁾	
		Y	Z
H	H	H	L
L	H	L	H
X	L	Z	Z

(1) H = high level, L = low level, X = irrelevant.

(2) Z = high impedance (off)

Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

9.2 Typical Application

When designing a system that uses drivers, receivers, and transceivers that comply with RS-422 or RS-485, proper cable termination is essential for highly reliable applications with reduced reflections in the transmission line. Because RS-422 allows only one driver on the bus, if termination is used, it is placed only at the end of the cable near the last receiver. In general, RS-485 requires termination at both ends of the cable. Factors to consider when determining the type of termination usually are performance requirements of the application and the ever-present factor, cost. The different types of termination techniques discussed are unterminated lines, parallel termination, ac termination, and multipoint termination

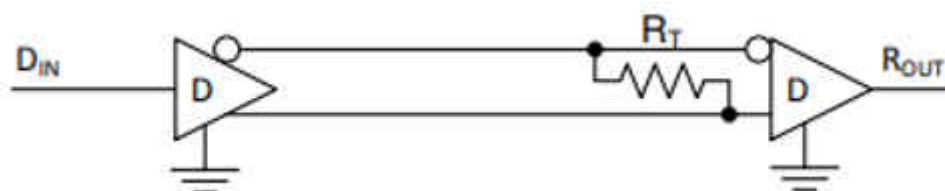


Figure 9-1. Typical RS-485 or RS-422 Application with Terminated Receiver.

9.2.1 Design Requirements

RS-485 is a robust electrical standard suitable for long-distance networking that may be used in a wide range of applications with varying requirements, such as distance, data rate, and number of nodes.

9.2.2 Detailed Design Procedure

9.2.2.1 Data Rate and Bus Length

There is an inverse relationship between data rate and cable length, which means the higher the data rate, the shorter the cable length; and conversely, the lower the data rate, the longer the cable length. While most RS-485 systems use data rates between 10 kbps and 100 kbps, some applications require data rates up to 250 kbps at distances of 4000 feet and longer. Longer distances are possible by allowing for small signal jitter of up to 5 or 10%.

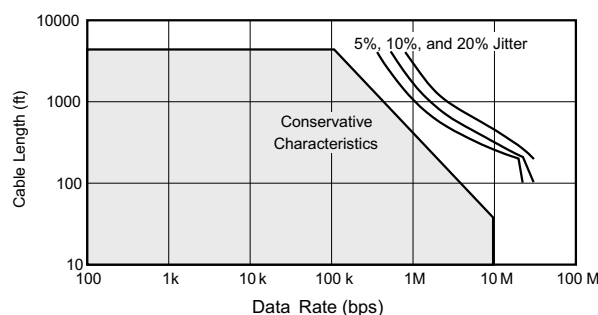


Figure 9-2. Cable Length vs Data Rate Characteristic

9.2.2.2 Stub Length

When connecting a node to the bus, the distance between the transceiver inputs and the cable trunk, known as the stub, should be as short as possible. Stubs present a non-terminated piece of bus line which can introduce reflections of varying phase as the length of the stub increases. As a general guideline, the electrical length, or round-trip delay, of a stub should be less than one-tenth of the rise time of the driver, thus giving a maximum physical stub length.

$$L_{\text{(STUB)}} \leq 0.1 \times t_r \times v \times c \quad (1)$$

where:

- t_r is the 10/90 rise time of the driver
- c is the speed of light (3×10^8 m/s)
- v is the signal velocity of the cable or trace as a factor of c

9.2.2.3 Bus Loading

The RS-485 standard specifies that a compliant driver must be able to drive 32 unit loads (UL), where 1 unit load represents a load impedance of approximately 12 k Ω .

9.3 Power Supply Recommendations

To ensure reliable operation at all data rates and supply voltages, each supply should be decoupled with a 100 nF ceramic capacitor located as close to the supply pins as possible. This helps to reduce supply voltage ripple present on the outputs of switched-mode power supplies and also helps to compensate for the resistance and inductance of the PCB power planes

9 Device and Documentation Support

9.1 Documentation Support

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](https://www.ti.com). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.4 Trademarks

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN75ALS174DW	LIFEBUY	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		75ALS174	
SN75ALS174DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75ALS174	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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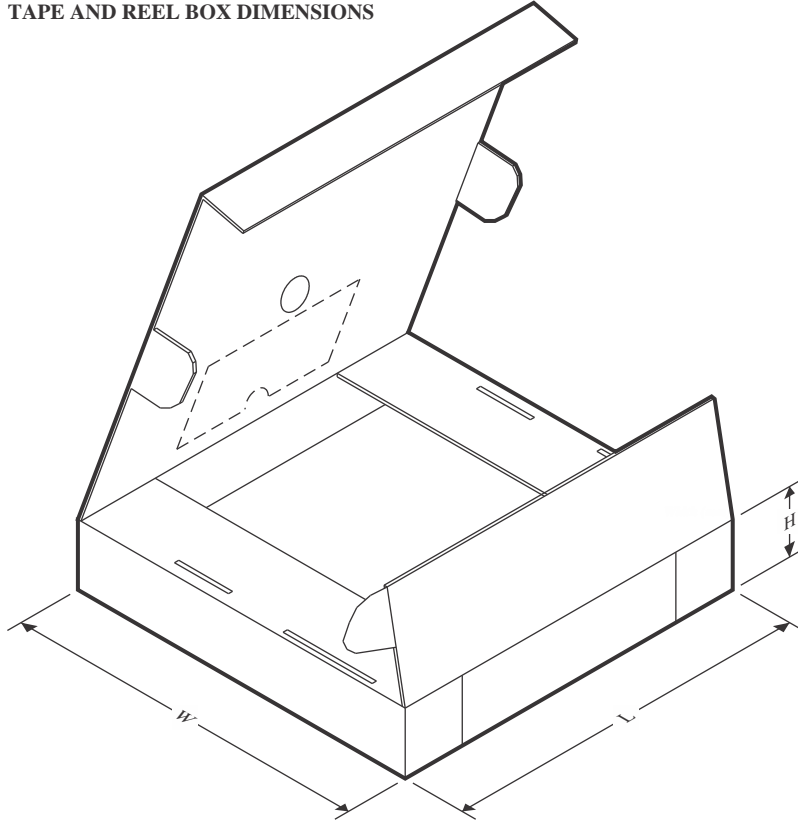
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75ALS174DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

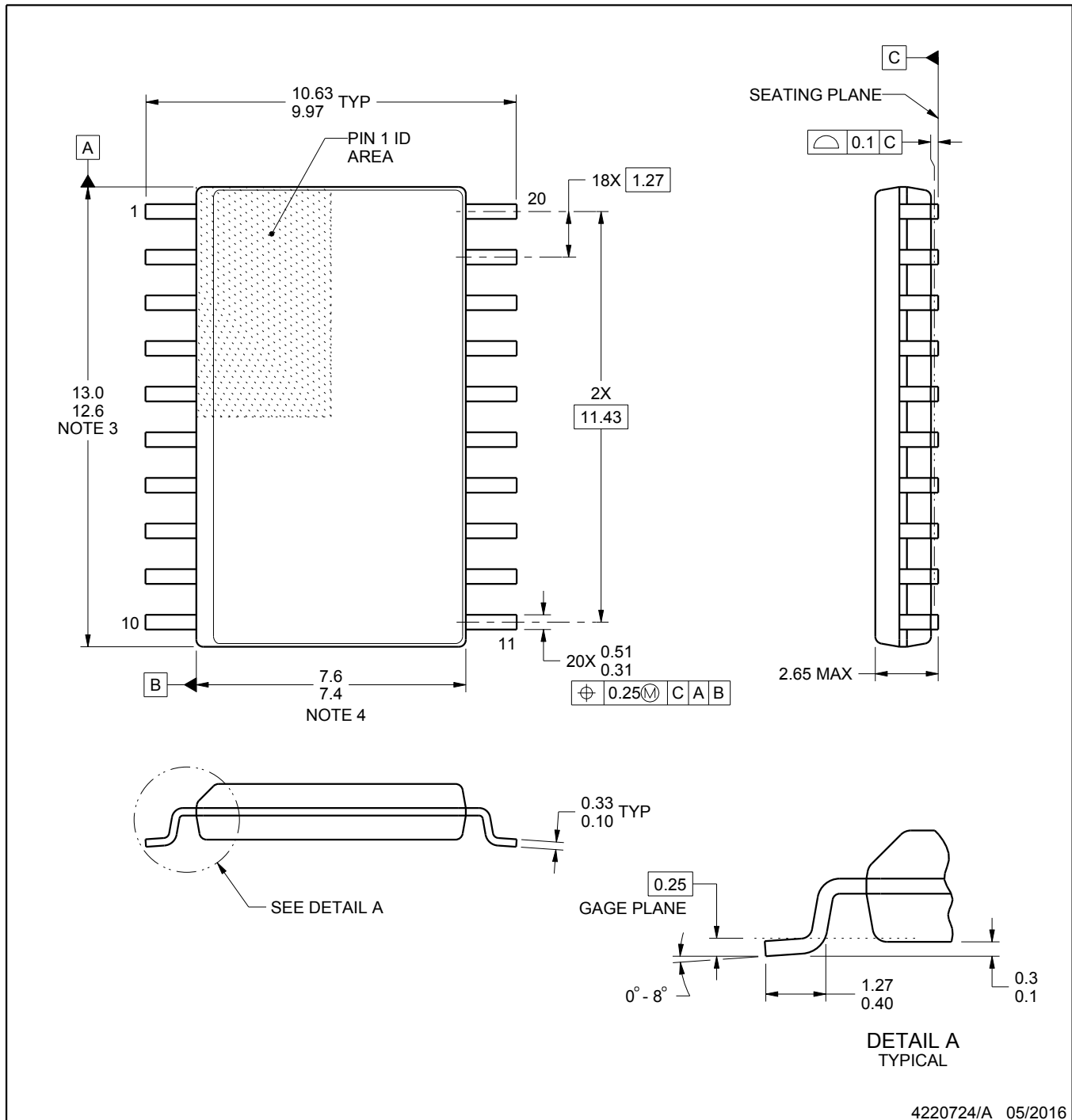
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75ALS174DWR	SOIC	DW	20	2000	367.0	367.0	45.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN75ALS174DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN75ALS174DW	DW	SOIC	20	25	506.98	12.7	4826	6.6



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NOTES:

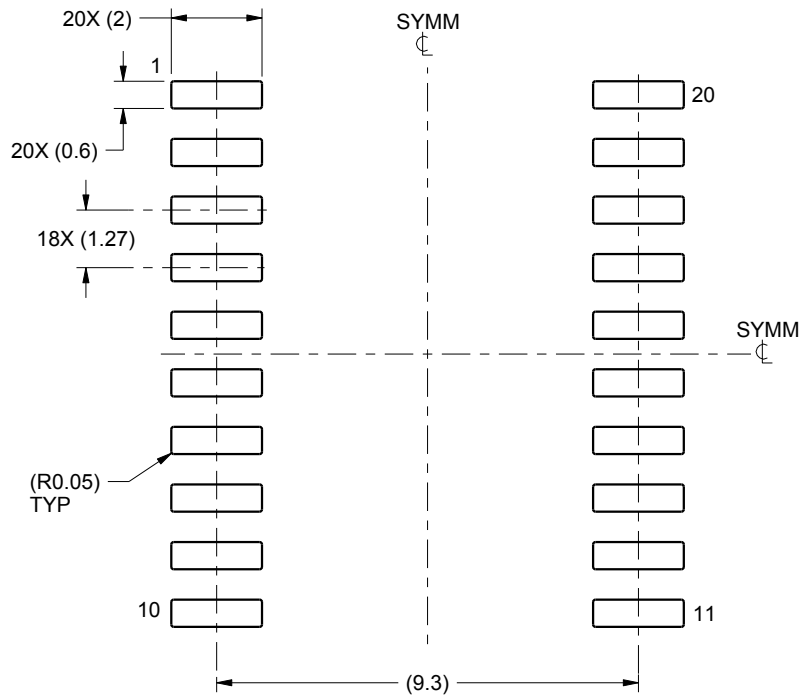
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

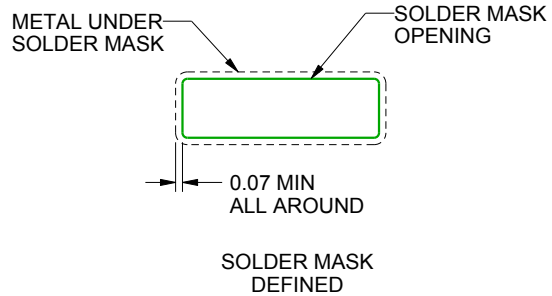
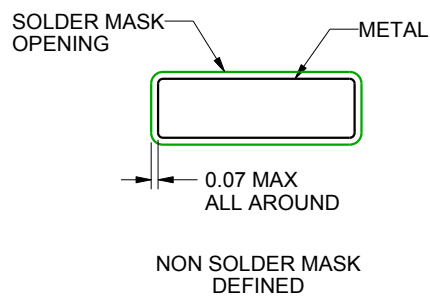
DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:6X



SOLDER MASK DETAILS

4220724/A 05/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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